

AS1364 DataSheet

1A, Low-Dropout Linear Voltage Regulator

1 General Description

The AS1364 is a low-dropout linear regulator (LDO) designed to operate from 2V to 5.5V input, that delivers a wide range of highly accurate (±0.75%) factory-trimmed output voltages as well as adjustable output voltages (using an external resistor-divider network).

The ultra-low dropout device requires only 140mV dropout voltage while delivering a guaranteed 1A load current and is therefore perfectly suited for battery-operated portable applications.

Additionally the AS1364 offers extremly low 10 μ VRMs (100Hz to 100kHz) or 45 μ VRMs (10Hz to 1MHz) output voltage noise.

Table 1. Standard Products

Model	Output Type	ВҮР	SET
AS1364-AD	Adjustable	No	Yes
AS1364	Fixed	Yes	No

The device features an internal PMOS pass transistor (for a low supply current of only 35 μ A), reset output, a low-power shutdown mode, and protection from short-circuit and thermal-overload conditions.

The AS1364 is available in an 8-pin TDFN 3x3mm package.

2 Key Features

Guaranteed Output Current: 1A

■ Low Dropout: 140mV @ 1A

Output Voltage Accuracy: Up to ±0.75%

■ 2.0 to 5.5V Input Voltage

■ Fixed VouT: 1.2 to 5.0V

■ Adjustable VouT: 1.2 to 5.0V

■ Low Ground Current: 35µA

Low Shutdown Current: 10nA

■ Low Output Noise: 45µVRMS (from 10Hz to 1MHz)

■ Thermal Overload Protection

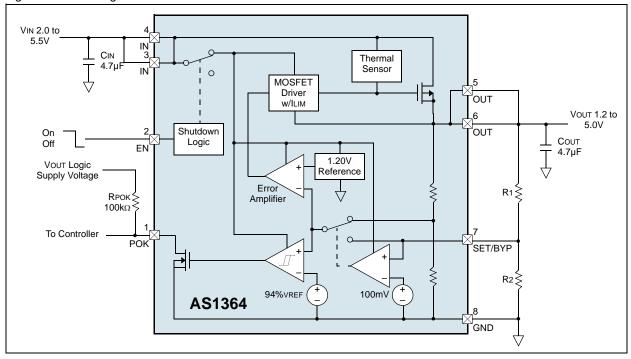
Output Current Limit

■ 8-pin TDFN 3x3mm Package

3 Applications

The device is ideal for laptops, PDAs, portable audio devices, mobile phones, cordless phones, and any other battery-operated portable device.



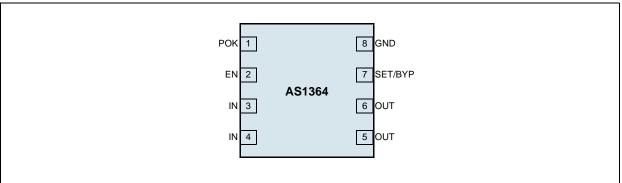




4 Pinout

Pin Assignments

Figure 2. Pin Assignments (Top View)



Pin Descriptions

Table 2. Pin Descriptions

Pin Number	Pin Name	Description
1	POK	Note: Open-Drain POK Output. POK remains low while VouT is below the POK threshold. Connect a $100k\Omega$ pull-up resistor from this pin to OUT to obtain an output voltage (see Figure 1 on page 1).
2	EN	Active-Low Shutdown Input. A logic low disables the output and reduces the supply current to 0.1µA. In shutdown, the POK output is low and OUT high impedance. VDD: Normal operation. GND: Shutdown.
3, 4	IN	2.0V to 5.5V Supply Voltage. Bypass with a 4.7μF input capacitor to GND (see Capacitor Selection and Regulator Stability on page 11). These inputs are internally connected, but they also must be externally connected for proper operation.
5, 6	OUT	Regulator Output . Bypass with a 4.7µF low-ESR output capacitor to GND. Connect the OUT pins together externally.
7	SET/BYP	Voltage-Setting Input. Connect to GND to select the factory-preset output voltage. Connect this pin to an external resistor-divider for adjustable-output operation (see Figure 1 on page 1). (AS1364-AD only) Bypass Pin. Connect a 10nF capacitor from this pin to OUT to improve PSRR and noise performance. (AS1364-AD does not offer this feature)
8	GND	Ground



5 Absolute Maximum Ratings

Stresses beyond those listed in Table 3 may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in Electrical Characteristics on page 4 is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Table 3. Absolute Maximum Ratings

Parameter	Min	Max	Units	Comments
IN, EN, POK to GND	-0.3	+7	V	
OUT, SET/BYP to GND	-0.3	VIN + 0.3	V	
Output Short-Circuit Duration		Infinite		
Thermal Resistance ⊕JA		36.3	°C/W	on PCB
ESD		2	kV	HBM MIL-Std. 883E 3015.7 methods
Latch-Up	-100	+100	mA	JEDEC 78
Operating Temperature Range	-40	+85	°C	
Storage Temperature Range	-65	+150	°C	
Junction Temperature		+150	°C	
Package Body Temperature		+260	°C	The reflow peak soldering temperature (body temperature) specified is in accordance with IPC/JEDEC J-STD-020C "Moisture/Reflow Sensitivity Classification for Non-Hermetic Solid State Surface Mount Devices". The lead finish for Pb-free leaded packages is matte tin (100% Sn).



6 Electrical Characteristics

VIN = VOUT + 500mV or VIN = +2.0V (whichever is greater), $CIN = COUT = 4.7\mu$ F, EN = IN, TAMB = -40 to $+85^{\circ}$ C (unless otherwise specified). Typical values are at $TAMB = +25^{\circ}$ C.

Table 4. Electrical Characteristics

Symbol	Parameter	Condition		Тур	Max	Unit	
VIN	Input Voltage		2.0		5.5	V	
Vpor	Power On Reset	Falling, 75mV hysteresis	1.79	1.87	1.95	V	
		IOUT = 250mA, TAMB = +25°C	-0.75		+0.75	%	
	Output Voltage Accuracy (Preset Mode)	IOUT = 250mA	-1.5		+1.5		
	(i reset Mode)	IOUT = 1mA to 1A, $VIN > (VOUT + 0.5V)^{1}$			+2		
Vout	Adjustable Output Voltage Range		1.2		5.0	V	
VSET/BYP	SET/BYP Voltage Threshold (Adjustable Mode)	VIN = 2.5V, IOUT = 250mA, VOUT set to 2.0V	1.17	1.20	1.23	V	
Іоит	Guaranteed Output Current (RMS)	VIN ≥ 2.0V	1			А	
ILIMIT	Short-Circuit Current Limit	$Vout = 0$, $Vin \ge 2.0V$	1.1	1.5	2.3	Α	
	In-Regulation Current Limit	Vout > 96% of nominal value, Vin $\geq 2.0V$		1.5		Α	
	SET/BYP Threshold		50	100	150	mV	
ISET	SET/BYP Input Bias Current	VSET/BYP = 1.20V	-100		+100	nA	
IQ	Ground-Pin Current	Ιουτ = 100μΑ		35	150		
IQ	Ground-Pin Current	IOUT = 1A		75	200	μA	
VIN -	2	IOUT = 250mA, VOUT = 3.3V		35	85	mV	
Vout	Dropout Voltage ²	IOUT = 1A, VOUT = 3.3V		140	320		
ΔV LNR	Line Regulation	VIN from (VOUT + 100mV) to 5.5V, ILOAD = 5mA	-0.125		+0.125	%/V	
$\Delta VLDR$	Load Regulation	egulation Iout = 1mA to 1A			0.001	%/mA	
		f = 1kHz, Iout = 10mA, CBYP = 10nF		78			
		f = 1kHz, Iout = 10mA		72			
PSRR	Dinala Daiastian	f = 10kHz, IOUT = 10mA, CBYP = 10nF	75			dB	
FORK	Ripple Rejection	f = 10kHz, IouT = 10mA		65		иь	
		f = 100kHz, Iout = 10mA, CBYP = 10nF		54			
		f = 100kHz, Iout = 10mA		46		1	
		100Hz to 100kHz, Cout = 3.3μF, CBYP = 10nF;	10				
	Output Voltage Noise	100Hz to 100kHz, Couτ = 3.3μF;		50		μVRMS	
	Output voitage Noise	10Hz to 1MHz, Cout = 3.3μF, CBYP = 10nF;		45		μνκινιδ	
		10Hz to 1MHz, Couт = 3.3µF;	70				



Table 4. Electrical Characteristics (Continued)

Symbol	Parameter	Condition	Min	Тур	Max	Unit	
Shutdown							
loff	Chutdown Cupply Current	EN = GND, $VIN = 5.5V$, $TAMB = 25$ °C		0.01	0.5		
IOFF	Shutdown Supply Current	EN = GND, VIN = 5.5V		0.1	15	μA	
ViH	CN Input Throphold	2.0V < VIN < 5.5V	: 5.5V 1.6			V	
VIL	EN Input Threshold	2.0V < VIN < 5.5V			0.6	V	
ISHDNN	EN Input Pigo Current	EN = IN or GND, TAMB = +25°C		1		nΛ	
ISHDININ	EN Input Bias Current	TAMB = +85°C		5		nA	
POK Output							
Vol	POK Output Low Voltage	POK sinking 1mA		0.05	0.25	V	
	Operating Voltage Range for Valid POK Signal	POK sinking 100μA	1.0		5.5	V	
	POK Output High leakage	$POK = 5.5V, TAMB = +25^{\circ}C$		1		nA	
	Current	TAMB = +85°C		5		IIA	
	POK Threshold	Rising edge (referenced to VouT(NOM))	90	94	98	%	
Thermal Protection							
TSHDNN	Thermal Shutdown Temperature			170	_	°C	
$\Delta TSHDNN$	Thermal Shutdown Hysteresis			20		°C	

^{1.} Guaranteed by production test of load regulation and line regulation.

^{2.} Dropout voltage is defined as VIN - VOUT, when VOUT is 100mV below the value of VOUT measured for VIN = (VOUT(NOM) + 500mV). Since the minimum input voltage is 2.0V, this specification is only valid when VOUT(NOM) > 2.0V.



7 Typical Operating Characteristics

VIN = VOUT + 0.5V, $CIN = COUT = 4.7\mu F$, $TAMB = 25^{\circ}C$ (unless otherwise specified).

Figure 3. VDROP vs. IOUT;

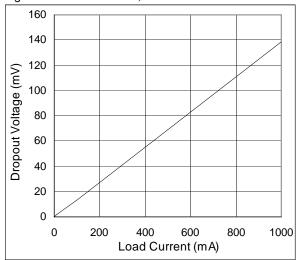


Figure 5. Vout vs. Temperature; Vout(Nom) = 3.3V

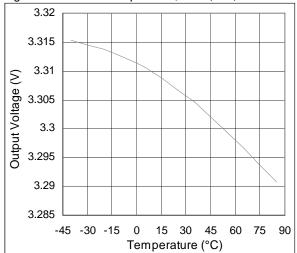


Figure 7. Quiescent Current vs. VIN;

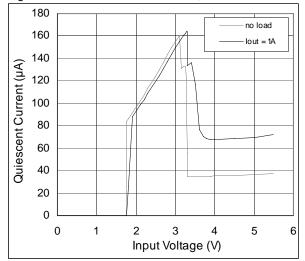


Figure 4. Vout vs. Vin; Vout(NOM) = 3.3V

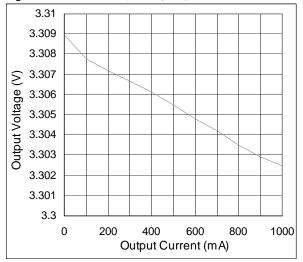


Figure 6. Vout vs. Vin; Vout(Nom) = 3.3V

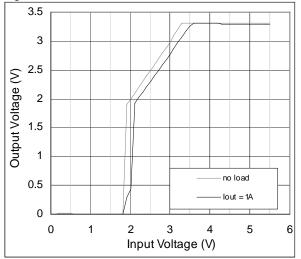
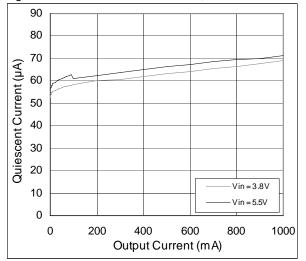


Figure 8. Quiescent Current vs. IOUT;



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Figure 9. Quiescent Current vs. Temperature;

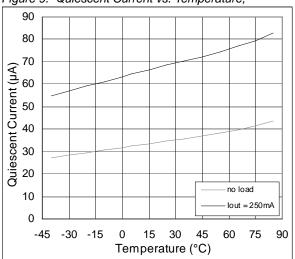


Figure 10. Spectral Noise vs. Freq.; IOUT = 10mA,

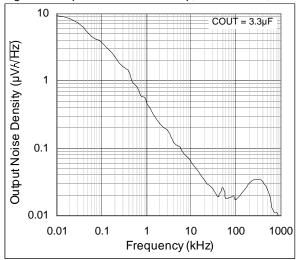


Figure 11. PSRR vs. Frequency; IOUT = 10mA

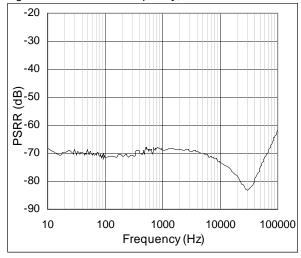




Figure 12. Line Transient Response; VIN = 3.8V to 4.3V, IOUT = 100mA

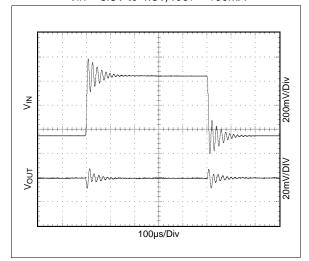


Figure 13. Load Transient Response; VIN = 3.8V, IOUT = 100mA to 1A

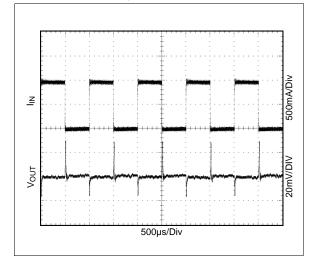


Figure 14. Startup; VIN = 3.8V, IOUT = 100mA

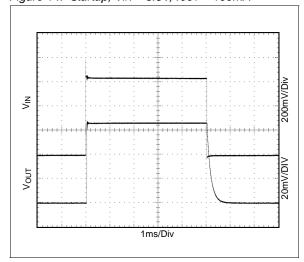
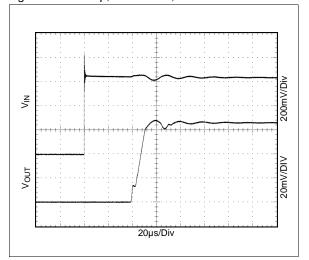


Figure 15. Startup; VIN = 3.8V, IOUT = 100mA

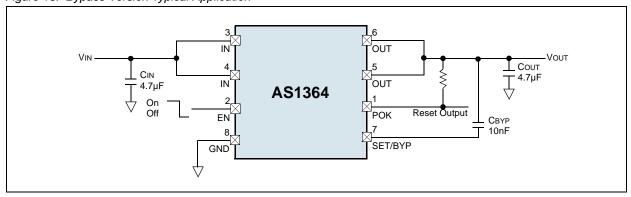




8 Detailed Description

The AS1364 output voltage is factory-trimmed or is adjustable from +1.2 to +5V, and is guaranteed to supply 1A of output current. The device consists of a +1.20V internal reference, error amplifier, MOSFET driver, P-channel pass transistor, internal feedback voltage-divider and a comparator (see Figure 1 on page 1).

Figure 16. Bypass Version Typical Application



The +1.20V reference is connected to the inverting input of the error amplifier, which compares this reference with the selected feedback voltage and amplifies the difference.

The MOSFET driver reads the error signal and applies the appropriate drive to the P-channel transistor. If the feedback voltage is lower than the reference, the pass transistor gate is pulled lower, allowing more current to pass increasing the output voltage. If the feedback voltage is too high, the pass transistor gate is pulled up, allowing less current to pass to the output.

The low Vout comparator senses when the feedback voltage has dropped 6% below its expected level, causing POK to go low.

The output voltage is fed back through either an internal resistor-divider connected to OUT or an external resistor network connected to SET. The comparator examines VSET/BYP and selects the feedback path. If VSET/BYP is below 50mV, the internal feedback path is used and the output is regulated to the factory-preset voltage.

Internal P-Channel Pass Transistor

The AS1364 features a 1A P-channel MOSFET pass transistor and consumes only a maximum of $200\mu A$ of quiescent current under heavy loads as well as in dropout.

Output Voltage Selection

At the factory trimmed versions of the AS1364 offering the bypass pin (see Figure 16), the output voltage is then set to an internally trimmed voltage (see Ordering Information on page 13).

For the adjustable AS1364-AD, an output voltage between +1.2V and +5V can be set by using two external resistors (see Figure 17). In this mode, VOUT is determined by:

$$VSET/BYP (1 + (R_1 / R_2))$$
 (EQ 1)

Where:

VSET/BYP = +1.20V.

A simplification of R1 and R2 selection is:

$$R1 = R2 ((VOUT / VSET/BYP) - 1)$$
 (EQ 2)

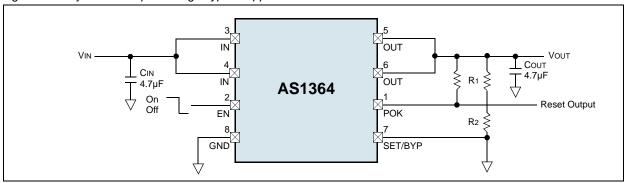
Since the input bias current at SET is less than 100nA, large resistance values can be used for R1 and R2 to minimize power consumption and therefore increasing efficiency.

Note: Up to $125k\Omega$ is acceptable for R2. If the SET pin is connected to GND without a resistor, 3.3V will be set as output voltage.

In preset voltage mode, the impedance from SET to GND should be less than $10k\Omega$ or spurious conditions may cause the voltage at SET to exceed the 50mV threshold.



Figure 17. Adjustable Output Voltage Typical Application



Shutdown

If pin EN is connected to GND the AS1364 is disabled. In shutdown mode all internal circuits are turned off, reducing supply current to 10nA (typ). For normal device operation pin EN must be connected to IN. During shutdown, POK goes low.

Power-OK

The AS1364 features a power-ok indicator that asserts when the output voltage falls out of regulation. The open-drain POK output goes low when output voltage at OUT falls 6% below its nominal value. A $100k\Omega$ pull-up resistor from POK to a (typically OUT) provides a logic control signal.

POK can be used as a power-on-reset (POR) signal to a microcontroller or can drive an external LED to indicate a power failure condition.

Note: POK is low during shutdown.

Current Limiter

The AS1364 features current limiting circuitry that monitors the pass transistor, limiting short-circuit output current to 1.5A (typ). The circuitry of the AS1364 allows that the output can be shorted to ground for an indefinite period of time without damaging the device.

Thermal Protection

Integrated thermal overload protection limits the total power dissipation in the AS1364. When the junction temperature (TJ) exceeds +170°C typically, the pass transistor is turned off. Normal operation is continued when TJ drops approximately 20°C.

Note: Regardless of the hysteresis, continuous short-circuit condition will result in a pulsed output.

Operating Region and Power Dissipation

Maximum power dissipation of the AS1364 depends on the thermal resistance of the package and the PCB, the temperature difference between the die junction and ambient air, and the rate of air flow.

The power dissipated in the device is given as:

$$PD = IOUT \sim (VIN - VOUT)$$
 (EQ 3)

The maximum power dissipation is calculated:

$$PDMAX = (T_{J(MAX)} - T_{AMB})/(\theta_{JC} + \theta_{CA})$$
 (EQ 4)

Where:

 $T_{J(MAX)}$ - TAMB is the temperature difference between the device die junction and the surrounding air. θ_{JC} is the thermal resistance of the junction to the case.

 θ CA is the thermal resistance from the case through the PCB, copper traces, and other materials to the surrounding air.

Connect the exposed thermal pad and GND to circuit ground by using a large pad, or multiple vias to the ground plane.



9 Application Information

Capacitor Selection and Regulator Stability

Input and output capacitors are required for stable operation of the AS1364 over the full temperature range and with load currents up to 1A. Connect CIN and COUT as close to the AS1364 as possible to minimize the impact of PC board trace inductance.

Input Capacitor

For CIN, a 4.7µF capacitor between IN and ground is sufficient. CIN reduces the source impedance of the input supply and may be smaller than 4.7µF if powered from regulated power supplies or low-impedance batteries. Larger input capacitor values and lower ESR provide better noise rejection and line-transient response.

Output Capacitor

A $4.7\mu F$ low-ESR capacitor between OUT and ground is sufficient for Cout. The output capacitor's ESR affects stability and output noise. An output capacitors with an ESR of 0.5Ω or less is recommended to ensure stability and optimum transient response. Reduced output noise and improve load-transient response, stability, and power-supply rejection by using large output capacitors with low ESR.

Noise, PSRR, and Transient Response

AS1364 output noise is typically $10\mu V_{RMS}$ (100Hz to 100kHz) or $45\mu V_{RMS}$ (10Hz to 1MHz) during normal operation. This is suitably low for most applications (see Figure 10 on page 7).

The AS1364 is designed to achieve extremly low dropout voltage and low quiescent current in battery-powered systems while still maintaining excellent noise performance, transient response, and PSRR. See the Figure 11 on page 7 for a plot of power-supply rejection ratio (PSRR) versus frequency.

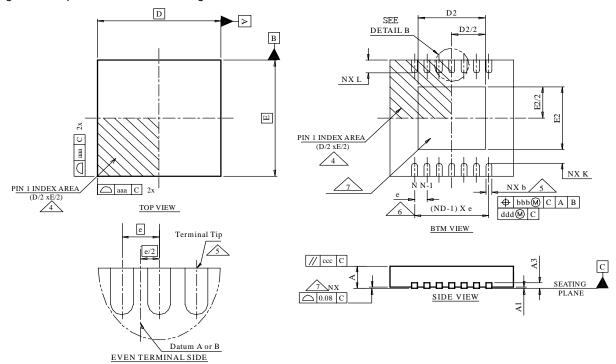
When operating from very noisy sources, the factory preset variants a recommanded since they offer improved noise performance over the adjustable variants.



10 Package Drawings and Markings

The device is available in an 8-pin TDFN 3x3mm package.

Figure 18. 8-pin TDFN 3x3mm Package



Symbol	Min	Тур	Max	Notes
Α	0.70	0.75	0.80	1, 2
A1	0.00	0.02	0.05	1, 2
А3		0.20 REF		1, 2
L1			0.15	1, 2
L2			0.13	1, 2
aaa		0.15		1, 2
bbb		0.10		1, 2
ccc		0.10		1, 2
ddd		0.05		1, 2
eee		0.08		1, 2
999		0.10		1, 2

Symbol	Min	Тур	Max	Notes
D BSC		3.00		1, 2
E BSC		3.00		1, 2
D2	1.60		2.50	1, 2
E2	1.35		1.75	1, 2
L	0.30	0.40	0.50	1, 2
θ	00		14º	1, 2
K	0.20			1, 2
b	0.25	0.30	0.35	1, 2, 5
е		0.65		
N		8		1, 2
ND		4		1, 2, 5

Notes:

- 1. Dimensioning and tolerancing conform to ASME Y14.5M-1994.
- 2. All dimensions are in millimeters, angle is in degrees.
- 3. N is the total number of terminals.
- 4. Terminal #1 identifier and terminal numbering convention shall conform to JESD 95-1 SPP-012. Details of terminal #1 identifier are optional, but must be located within the area indicated. The terminal #1 identifier may be either a mold, embedded metal or mark feature.
- 5. Dimension b applies to metallized terminal and is measured between 0.15 and 0.30mm from terminal tip.
- 6. ND refers to the maximum number of terminals on D side.
- 7. Unilateral coplanarity zone applies to the exposed heat sink slug as well as the terminals.



11 Ordering Information

The device is available as the standard products shown in Table 5.

Table 5. Ordering Information

Model	Marking	Output	SET/BYP	Delivery Form	Package
AS1364-BTDT-AD	ASRF	adjustable (preset to 3.3V)	SET	Tape and Reel	8-pin TDFN 3x3mm
AS1364-BTDT-12*	ASRN	1.2V	BYP	Tape and Reel	8-pin TDFN 3x3mm
AS1364-BTDT-15*	ASRA	1.5V	BYP	Tape and Reel	8-pin TDFN 3x3mm
AS1364-BTDT-18*	ASRB	1.8V	BYP	Tape and Reel	8-pin TDFN 3x3mm
AS1364-BTDT-30*	ASRC	3.0V	BYP	Tape and Reel	8-pin TDFN 3x3mm
AS1364-BTDT-33*	ASRD	3.3V	BYP	Tape and Reel	8-pin TDFN 3x3mm
AS1364-BTDT-45*	ASRE	4.5V	BYP	Tape and Reel	8-pin TDFN 3x3mm

All devices are RoHS compliant and free of halogene substances.

Non-standard devices are available between 1.4V and 4.6V in 50mV steps and between 4.6V and 5.0V in 100mV steps. For more information and inquiries contact http://www.austriamicrosystems.com/contact

^{*}Future product.



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